
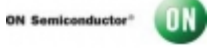
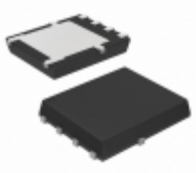
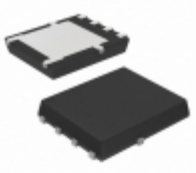
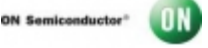
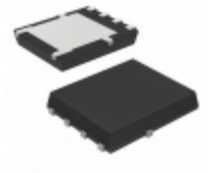
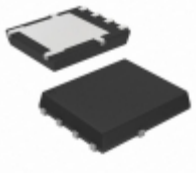
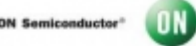
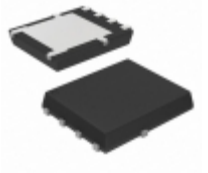
	<h2 style="color: red;">NVMFS4C302NT1G</h2>
	<p>Hersteller-Teilenummer: NVMFS4C302NT1G</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: NFET S08FL 30V 1.15MO</p> <hr/> <p>Datenblätter:  NVMFS4C302NT1G.pdf</p> <hr/> <p>RoHs Status:</p> <hr/> <p>Lagerzustand: New original, Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NVMFS4C302NT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	NFET S08FL 30V 1.15MO
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	Require For Quote & Check Stock
VGS (th) (Max) @ Id	2.2V @ 250µA
Vgs (Max)	±20V
Technologie	MOSFET (Metal Oxide)
Supplier Device-Gehäuse	5-DFN (5x6) (8-SOFL)
Serie	Automotive, AEC-Q101
Rds On (Max) @ Id, Vgs	1.15 mOhm @ 30A, 10V
Verlustleistung (max)	3.75W (Ta), 115W (Tc)
Verpackung / Gehäuse	8-PowerTDFN, 5 Leads
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Hersteller Standard Vorlaufzeit	42 Weeks
Bleifreier Status	Lead free
Eingabekapazität (Ciss) (Max) @ Vds	5780pF @ 15V
Gate Charge (Qg) (Max) @ Vgs	82nC @ 10V
Typ FET	N-Channel
FET-Merkmal	-
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Drain-Source-Spannung (Vdss)	30V
detaillierte Beschreibuna	N-Channel 30V 43A (Ta), 241A (Tc) 3.75W (Ta), 115W
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	43A (Ta), 241A (Tc)

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RFQ NVMFS4C302NT1G E-Mail: Info@Y-IC.com

Sie können auch interessiert

<p>sein:</p>  <p>NVMFS4C310NWFT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V TRENCH</p>	 <p>NVMFS4C05NT3G ON Semiconductor MOSFET N-CH 30V 116A SO8FL</p>	 <p>NVMFS4C05NWFT1G ON Semiconductor MOSFET N-CH 30V 116A SO8FL</p>	 <p>NVMFS4C05N ON NVMFS4C05N ON</p>
 <p>NVMFS4C310NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V TRENCH</p>	 <p>NVMFS4C05NT1G ON Semiconductor MOSFET N-CH 30V 116A SO8FL</p>	 <p>NVMFS4C310NWFT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V TRENCH</p>	 <p>NVMFS4C05NWFT3G ON Semiconductor MOSFET N-CH 30V 116A SO8FL</p>

Verwandtes Hot-Keyword

Mehr

NVMFS4C302NT1G AMI Semiconductor / ON Semiconductor	NVMFS4C302NT1G Datenblatt	NVMFS4C302NT1G-Datenblätter	NVMFS4C302NT1G PDF	AMI Semiconductor / ON Semiconductor NVMFS4C302NT1G
NVMFS4C302NT1G Electronic	NVMFS4C302NT1G-Komponenten	NVMFS4C302NT1G-Verteiler	NVMFS4C302NT1G-Bild	NVMFS4C302NT1G-Teil
NVMFS4C302NT1G Preis	NVMFS4C302NT1G Hersteller	NVMFS4C302NT1G Bild	NVMFS4C302NT1G Aktie	NVMFS4C302NT1G Inventar
NVMFS4C302NT1G Neu	NVMFS4C302NT1G Original	NVMFS4C302NT1G garantiert	NVMFS4C302NT1G RFQ	NVMFS4C302NT1G Online bestellen

Contact us: Info@Y-IC.com

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